NSN 5961-01-201-5601

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-201-5601 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **End Application:** Armament, fire control, an/asq-165 **Internal Configuration:** Point contact **Mounting Method:** Press fit **Features Provided:** Quality assurance level txv and burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** Between 1.00 amperes all primaries and 3.00 amperes all primaries blank **Power Rating Per Characteristic:** 15.0 watts collector power dissipation peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No